L Number	Hits	Search Text	DB	Time stamp
·	1667	250/205;438/7,16.ccls.	USPAT;	2002/11/21
-	1001	200/200, 100/1, 101/01/01	US-PGPUB;	11:08
			DERWENT	
	144	(reaction NEAR4 chamber) AND (pulse	USPAT;	2002/11/21
•	144	NEAR3 light) AND intensity	US-PGPUB;	09:54
		NEARS light) AND intensity	DERWENT	
	4	250/205;438/7,16.ccls. AND ((reaction	USPAT;	2002/11/21
-	1	NEAR4 chamber) AND (pulse NEAR3 light)	US-PGPUB;	09:56
			DERWENT	55.55
	46	AND intensity)	USPAT;	2002/11/21
-	46	metrology AND 250/205;438/7,16.ccls.	US-PGPUB;	09:56
			DERWENT	00.00
		(AD Labourhou) AND (motrology	USPAT;	2002/11/21
•	1	(reaction ADJ chamber) AND (metrology	US-PGPUB;	10:40
		AND 250/205;438/7,16.ccls.)	DERWENT	10.40
	420	449/004	USPAT:	2002/11/21
-	132	118/691.ccls.	US-PGPUB;	10:42
			DERWENT	
	19	semiconductor AND 118/691.ccls.	USPAT;	2002/11/21
•	19	Semiconductor AND 110/03 ficeis.	US-PGPUB;	10:56
			DERWENT	
	0	pulse WITH intensity WITH cutoff AND	USPAT;	2002/11/21
•	U	(250/205;438/7,16.ccls. OR 118/691.ccls.)	US-PGPUB;	10:57
		(230/203,430/7,10/03/81 01/11/03/81	DERWENT	
_	32	pulse WITH intensity WITH (cutoff OR (cut	USPAT;	2002/11/21
	0_	ADJ off))	US-PGPUB;	10:58
			DERWENT	
-	8	light WITH pulse WITH intensity WITH	USPAT;	2002/11/21
	-	(cutoff OR (cut ADJ off))	US-PGPUB;	10:58
			DERWENT	
-	1019	250/205.ccls.	USPAT;	2002/11/21
			US-PGPUB;	11:08
			DERWENT	
-	349	250/205.ccls. AND pulse	USPAT;	2002/11/21
			US-PGPUB;	11:08
			DERWENT	
-	37	(250/205.ccls. AND pulse) AND (cutoff OR	USPAT;	2002/11/21
		(cut ADJ off))	US-PGPUB;	13:02
			DERWENT	
-	6	((xenon OR flash) NEAR5 (lamp OR light))	USPAT;	2002/11/21
		AND ((250/205.ccls. AND pulse) AND (cutoff	US-PGPUB;	11:11
		OR (cut ADJ off)))	DERWENT	0000/44/24
•	1	light NEAR4 puls\$4 AND ((endpoint NEAR7	USPAT;	2002/11/21
		detect\$4) AND (semiconductor AND	US-PGPUB;	13:05
		"reaction chamber" AND endpoint))	DERWENT	2002/11/22
•	95	(endpoint NEAR7 detect\$4) AND	USPAT;	14:20
		(semiconductor AND "reaction chamber"	US-PGPUB; DERWENT	17.20
		AND endpoint)	JPO	2002/11/21
-	0	semiconductor AND "reaction chamber"	JF O	13:34
		AND endpoint		

-	2	("5151595"). PN .	USPAT;	2002/11/21
			US-PGPUB;	16:34
			DERWENT	
-	21	endpoint.ti. AND semiconductor AND	USPAT;	2002/11/22
		"reaction chamber"	US-PGPUB;	14:22
			DERWENT	
-	12	integrat\$4 AND endpoint.ti. AND	USPAT;	2002/11/22
		semiconductor AND "reaction chamber"	US-PGPUB;	14:26
			DERWENT	
-	2	(pulse NEAR5 (light OR laser)) AND	USPAT;	2002/11/22
		semiconductor AND "reaction chamber"	US-PGPUB;	14:27
		AND (endpoint NEAR7 detect\$4)	DERWENT	0000/44/22
-	9	(US-5705808-\$ or US-6231774-\$ or	USPAT;	2002/11/22
		US-6429928-\$ or US-6395563-\$ or	US-PGPUB	15:21
		US-5969805-\$ or US-5151584-\$ or		
		US-5969335-\$ or US-5285058-\$).did. or		
	_	(US-20010009459-\$).did.	USPAT;	2002/11/22
-	0	("(etching OR deposition OR semiconductor)	US-PGPUB;	15:24
		AND (light NEAR7 external) AND	DERWENT	13.24
	•	(pulse)").PN.	USPAT;	2002/11/22
-	0	("(etching OR deposition OR semiconductor)	US-PGPUB;	15:24
		AND (light NEAR7 external)").PN.	DERWENT	
	9404	(etching OR deposition OR semiconductor)	USPAT;	2002/11/22
•	8104	AND (light NEAR7 external)	US-PGPUB;	15:24
		AND (light NEAR) external)	DERWENT	
	2551	(etching OR deposition OR semiconductor)	USPAT;	2002/11/22
-	2331	AND (light NEAR7 external) AND (pulse)	US-PGPUB;	15:25
		(iight in the control of the control	DERWENT	
_	6	(endpoint NEAR7 detect\$4) AND ((etching	USPAT;	2002/11/22
	_	OR deposition OR semiconductor) AND (light	US-PGPUB;	15:25
		NEAR7 external) AND (pulse))	DERWENT	
	47	"reaction chamber" AND ((etching OR	USPAT;	2002/11/22
		deposition OR semiconductor) AND (light	US-PGPUB;	15:26
		NEAR7 external) AND (pulse))	DERWENT	
-	97	semiconductor AND pulse AND light AND	EPO; JPO	2002/11/25
		manufacture		10:33
-	10	grimbergen.in.	USPAT;	2002/11/25
			US-PGPUB	11:46
-	13	(light ADJ detector) WITH (filter ADJ	USPAT;	2002/11/25
		element)	US-PGPUB	11:47 2002/11/25
-	4355	light AND detector AND feedback AND	USPAT;	14:12
		(cutoff OR cut ADJ off)	US-PGPUB; DERWENT	14.12
		A DAND HELL AND	USPAT;	2002/11/25
-	214	(intensity SAME integrated) AND (light AND	US-PGPUB;	14:12
		detector AND feedback AND (cutoff OR cut	DERWENT	
	4 40	ADJ off)) pulse AND ((intensity SAME integrated) AND	USPAT;	2002/11/25
-	148	(light AND detector AND feedback AND	US-PGPUB;	14:12
		(cutoff OR cut ADJ off)))	DERWENT	
	85	capacitor AND (pulse AND ((intensity SAME	USPAT;	2002/11/25
•	63	integrated) AND (light AND detector AND	US-PGPUB;	15:50
		feedback AND (cutoff OR cut ADJ off))))	DERWENT	
		TO THE LOCATION OF THE PARTY OF		

		_		
	0	5705808.URPN.	USPAT	2002/11/25 14:19
		("3033988" "3350604" "3648104" "3684917" "4249109" "5134273"	USPAT	2002/11/25 14:19
1	372	"5151595").PN. light WITH (power OR current OR energy) WITH (cut ADJ off OR cutoff)	USPAT; US-PGPUB;	2002/11/25 15:51
		William (car Abb on on outon)	DERWENT	
		(light WITH (power OR current OR energy) WITH (cut ADJ off OR cutoff)) SAME integrate\$2	USPAT; US-PGPUB; DERWENT	2002/11/25 15:51
		(("6060397") or ("6122042")). PN .	USPAT; US-PGPUB; DERWENT	2002/11/26 16:26
		semiconductor AND "reaction chamber" AND endpoint	USPAT; US-PGPUB;	2002/11/26 16:44
	75	intensity AND (semiconductor AND "reaction chamber" AND endpoint)	USPAT; US-PGPUB;	2002/11/26 16:32
	14	pulse AND (intensity AND (semiconductor AND "reaction chamber" AND endpoint))	USPAT; US-PGPUB;	2002/11/26 16:33
	346	semiconductor AND "reaction chamber" AND (endpoint OR end ADJ point)	USPAT; US-PGPUB;	2002/11/26 16:45
	150	intensity AND (semiconductor AND "reaction chamber" AND (endpoint OR end ADJ point))	USPAT; US-PGPUB;	2002/11/26 16:45
	34	pulse AND (intensity AND (semiconductor AND "reaction chamber" AND (endpoint OR	DERWENT USPAT; US-PGPUB;	2002/11/26 17:04
	9287	end ADJ point))) (feedback OR cutoff OR cut ADJ off OR intensity ADJ control) AND (endpoint OR end	DERWENT USPAT; US-PGPUB; DERWENT	2002/11/26 17:06
. 9	9287	ADJ point) (feedback OR (cutoff OR cut ADJ off) OR (intensity ADJ control)) AND (endpoint OR	USPAT; US-PGPUB; DERWENT	2002/11/26 17:07
	533	end ADJ point) (semiconductor NEAR7 (manufacture OR process)) AND ((feedback OR (cutoff OR cut ADJ off) OR (intensity ADJ control)) AND	USPAT; US-PGPUB; DERWENT	2002/11/26 17:08
-	128	(endpoint OR end ADJ point)) (light NEAR7 intensity) AND ((semiconductor NEAR7 (manufacture OR process)) AND ((feedback OR (cutoff OR cut ADJ off) OR (intensity ADJ control)) AND (endpoint OR	USPAT; US-PGPUB; DERWENT	2002/11/26 17:35
- :	3492	end ADJ point))) capacitor WITH laser	USPAT; US-PGPUB; DERWENT	2002/11/26 17:35
-	1112	pulse SAME (capacitor WITH laser)	USPAT; US-PGPUB; DERWENT	2002/11/26 17:35

3386 250/205,206;438/7,14,16,17.ccls.

381 pulse AND intensity AND 250/205,206;438/7,14,16,17.ccls. USPAT;

2002/11/27

US-PGPUB;

11:00

DERWENT

USPAT;

2002/11/27

US-PGPUB; 11:00 DERWENT